



Headphone Driver

PT2308

DESCRIPTION

PT2308 is a Class AB stereo headphone driver chip utilizing CMOS Technology specially designed for portable digital audio applications. It is housed in an 8-pin DIP or SO package and is functionally compatible with TDA1308. Pin assignments and application circuit are optimized for lower cost effectiveness and easy PCB Layout

FEATURES

- CMOS Technology
- Low Power Consumption
- Wide Temperature Range
- Excellent Power Supply Ripple Rejection
- High Signal-to-Noise Ratio, S/N=110dB
- Low Harmonic Distortion, THD= 0.001%
- Large Output Voltage Swing

APPLICATIONS

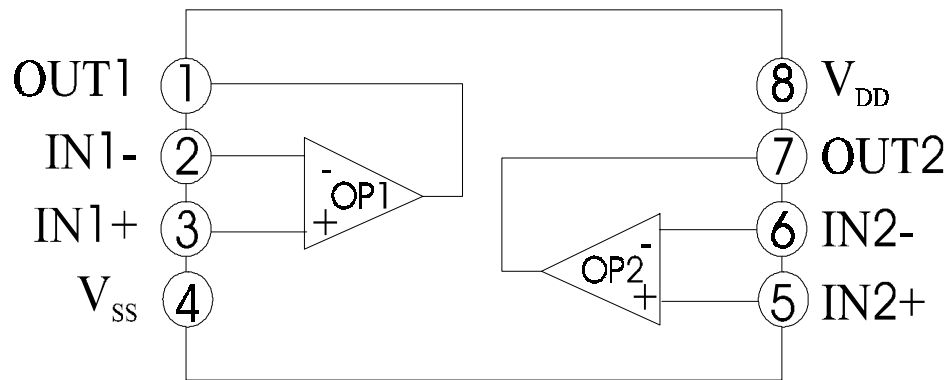
- Portable Digital Audio
- Hi-fi Audio System
- Walkman
- CD-ROM



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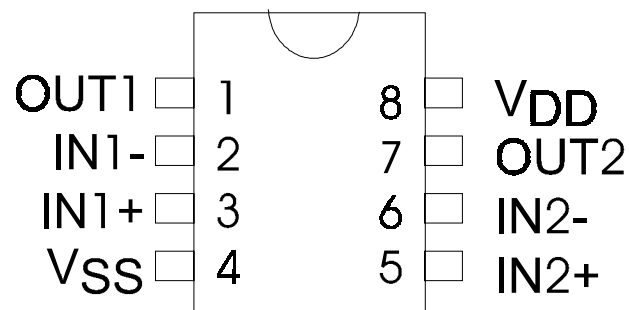
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BLOCK DIAGRAM



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PIN CONFIGURATION



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PIN DESCRIPTION

Symbol	I/O	Description	Pin No.
OUT1	O	Output Pin 1	1
IN1-	I	Inverting Input Pin 1	2
IN1+	I	Non-Inverting Input Pin 1	3
V_{SS}	-	Negative Power Supply	4
IN2+	I	Non-Inverting Input Pin 2	5
IN2-	I	Inverting Input Pin2	6
OUT2	O	Output Pin 2	7
V_{DD}	-	Positive Power Supply	8



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ELECTRICAL PARAMETERS

(Unless otherwise stated, V_{DD}=5V, V_{SS}=0V, T_{amb}=25°C, f_{in}=1 KHz, R_L=32 Ohms)

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
V _{DD}	Single Supply Voltage		3.0	5.0	7.0	V
	Dual Supply Voltage		1.5	2.5	3.5	V
V _{SS}	Negative Power Supply		-1.5	-2.5	-3.5	V
I _{DD}	Supply Current	No Load	-	7.0	-	mA
P _{tot}	Total Power Dissipation	No Load	-	35	-	mW
P _o	Maximum Output Power		-	60	-	mW
THD	Total Harmonic Distortion	V _o (p-p)=3.5V	-	0.03	0.06	%
		V _o (p-p)=3.5V R _L =5 K Ohms	-	0.001	-	
S/N	Signal-to-Noise Ratio		100	110	-	dB
α_{CS}	Channel Separation		-	70	-	dB
		R _L =5 K Ohms	-	105	-	
PSRR	Power Supply Ripple Rejection	f _{in} =100Hz V _{ripple} (p-p)=100mV	-	90	-	dB



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ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Rating	Unit
V _{DD}	Supply Voltage	8	V
T _{amb}	Operating Ambient Temperature	-40 to +85	°C
T _{stg}	Storage Temperature	-65 to +150	°C

APPLICATION CIRCUIT

